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H-type Ce₂[Si₂O₇]

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The title compound, dicerium(III) oxidodisilicate, $Ce_2[Si_2O_7]$, was obtained as a by-product in its *H*-type structure after attempts to synthesize $CeSb_2O_4Cl$ from fused silica ampoules. It crystallizes isotypically with *H*-La₂[Si₂O₇]. The four crystallographically distinct Ce^{III} cations form distorted square antiprisms, capped square antiprisms, and bicapped square antiprisms as coordination polyhedra consisting of oxygen atoms. Four crystallographically different silicon atoms recruit the centers of two different isolated $[Si_2O_7]^{6-}$ units.



Structure description

H-type Ce₂[Si₂O₇], like H-La₂[Si₂O₇] (Müller-Bunz & Schleid, 2000), crystallizes isotypically with the triclinic form of potassium dichromate [K₂[Cr₂O₇]; Brandon & Brown, 1968] in the space group $P\overline{1}$. According to the single-crystal X-ray structure analysis, four crystallographically distinct Ce^{III} cations with coordination numbers ranging from eight to ten are present (Fig. 1), with oxygen atoms forming distorted square antiprisms (Ce2), capped square antiprisms (Ce4), and bicapped square antiprisms (Ce1 and Ce3) as coordination polyhedra. The cerium-oxygen distances d(Ce-O) cover an interval from 2.366 (4) to 2.817 (4) Å (Table 1) plus 3.11 (4)-3.34 (4) Å to most caps. All oxygen atoms belong to pyroanionic oxidodisilicate anions [Si₂O₇]⁶⁻ (Fig. 2), each consisting of two vertex-connected [SiO₄]⁴⁻ tetrahedra. Here, four crystallographically different silicon atoms recruit the centers of these two isolated $[Si_2O_7]^{6-}$ units [d(Si-O) = 1.588 (4)-1.676 (4) Å (Table 1); \angle (O-Si-O) = 100.67 (19)-117.4 (2)°]. Both exhibit an ecliptical conformation with Si-O-Si angles of 129.2 (2) and 128.8 (2)°, leading to a backboneto-backbone alignment of the Si-O-Si bridges. The silicon-oxygen distances are in the usual range for this element combination, with slightly longer contacts to the bridging oxygen atoms (Table 1). The shortest, of course non-bonding, cerium-silicon distances of 3.2118 (14)–3.3391 (14) Å reflect the close proximity of Ce^{III} to the discrete $[Si_2O_7]^{6-1}$ anions. Figure 3 shows the content of an extended unit-cell with highlighted [Si₂O₇]⁶⁻



Table 1			
Selected	l bond	lengths	(Å).

Ce1-O6	2.386 (4)	Ce3-O1 ^{vii}	2.396 (4)
Ce1-O13	2.439 (4)	Ce3–O7	2.457 (4)
Ce1-O12	2.445 (4)	Ce3–O2 ⁱⁱⁱ	2.490 (4)
Ce1-O10	2.480 (4)	Ce3–O3 ^{iv}	2.534 (4)
Ce1-O14 ⁱ	2.486 (4)	Ce3-O6	2.555 (4)
Ce1-O9 ⁱⁱ	2.516 (4)	Ce3-O13	2.632 (4)
Ce1-O11 ⁱ	2.663 (4)	Ce3-O14	2.687 (4)
Ce1-Si4 ⁱ	3.2597 (15)	Ce3–O4 ⁱⁱⁱ	2.705 (4)
Ce1-Si2	3.3340 (15)	Ce3-Si4	3.2767 (15)
Ce1-Si3	3.4775 (14)	Ce3-Si1 ⁱⁱⁱ	3.3138 (14)
Ce1-Ce3	3.9086 (4)	Ce3-Si2 ^{ix}	3.3545 (14)
Ce1-Ce4 ⁱⁱ	3.9449 (4)	Ce3-Si1 ^x	3.4591 (15)
Ce2-O8	2.366 (4)	Si1-O1 ⁱⁱⁱ	1.592 (4)
Ce2-O2	2.370 (4)	Si1-O2	1.624 (4)
Ce2-O12	2.376 (4)	Si1-O3	1.632 (4)
Ce2-O10	2.494 (4)	Si1-O4	1.664 (4)
Ce2-O10 ⁱⁱⁱ	2.526 (4)	Si1-Ce3 ⁱⁱⁱ	3.3138 (14)
Ce2-O13 ⁱⁱⁱ	2.643 (4)	Si1-Ce4 ⁱⁱⁱ	3.4549 (14)
Ce2-O9 ⁱⁱⁱ	2.675 (4)	Si1-Ce3xi	3.4591 (15)
Ce2-O3	2.817 (4)	Si2-O5	1.589 (4)
Ce2-Si1	3.2118 (14)	Si2-O7 ⁱ	1.636 (4)
Ce2-Si3 ⁱⁱⁱ	3.2386 (15)	Si2-O6	1.642 (4)
Ce2-Si4 ^{iv}	3.4514 (15)	Si2-O4 ^x	1.660 (4)
Ce2-Ce1 ⁱⁱⁱ	3.9450 (4)	Si2-Ce4 ⁱⁱ	3.3391 (14)
Ce4-O5	2.415 (4)	Si2-Ce3 ⁱ	3.3544 (14)
Ce4-O1	2.420 (4)	Si3-O8 ^v	1.595 (4)
Ce4-O3 ^v	2.517 (4)	Si3-O9	1.632 (4)
Ce4-O7 ^{vi}	2.576 (4)	Si3-O10	1.641 (4)
Ce4-O7 ^{vii}	2.603 (4)	Si3-O11 ⁱⁱⁱ	1.648 (4)
Ce4-O8 ^v	2.655 (4)	Si3-Ce2 ⁱⁱⁱ	3.2386 (15)
Ce4-O14vi	2.681 (4)	Si4-O12 ^{iv}	1.588 (4)
Ce4-O9	2.749 (4)	Si4-O13	1.620 (4)
Ce4-O6 ^{viii}	2.812 (4)	Si4-O14	1.631 (4)
Ce4-Si3	3.2807 (14)	Si4-O11	1.676 (4)
Ce4-Si2viii	3.3391 (14)	Si4-Ce1 ^{ix}	3.2597 (15)
Ce4-Si1 ⁱⁱⁱ	3.4549 (14)	Si4-Ce2 ^{iv}	3.4514 (15)



Figure 1

Oxygen environment of the four crystallographically different Ce^{III} cations in *H*-type $Ce_2[Si_2O_7]$. The yellow dotted bonds reflect cerium-oxygen distances longer than 3.0 Å. Displacement ellipsoids are drawn at the 95% probability level. Symmetry codes refer to Table 1.



Figure 2

The two distinct oxidodisilicate anions $[Si_2O_7]^{6-}$ made of two vertexconnected $[SiO_4]^{4-}$ tetrahedra in *H*-type Ce₂[Si₂O₇], where the position of the oxygen atoms define a backbone arrangement (*left*), and their *Newman* projection (*right*). Displacement ellipsoids are drawn at the 95% probability level. Symmetry codes refer to Table 1.

bitetrahedra. The similarity to the other so-far known polymorphs of Ce₂[Si₂O₇] [*A*- (Kępiński *et al.*, 2002; Deng & Ibers, 2005) and *G*-type (Tas & Akinc, 1994; Christensen, 1994; Christensen & Hazell, 1994) and even *I*-type Ce₂Si₂O₇ (\equiv Ce₆[Si₄O₁₃][SiO₄]₂) (Kępiński *et al.*, 2002)] is striking and will be discussed in an upcoming review article (Hartenbach *et al.*, 2023) as a follow up of the pioneering one by Felsche (1970).

Synthesis and crystallization

Single crystals of H-Ce₂[Si₂O₇] were obtained as a by-product during the synthesis of CeSb₂O₄Cl (Locke, 2023; Weis, 2023) by reacting Ce₂O₃ with fused silica (SiO₂) as reaction vessel at



Figure 3

View of the triclinic crystal structure of *H*-type $Ce_2[Si_2O_7]$ along [100] emphasizing the discrete $[Si_2O_7]^{6-}$ anions. Displacement ellipsoids are drawn at the 95% probability level.

Table 2Experimental details.

Crystal data	
Chemical formula	$Ce_2[Si_2O_7]$
M _r	448.42
Crystal system, space group	Triclinic, P1
Temperature (K)	293
<i>a</i> , <i>b</i> , <i>c</i> (Å)	6.7671 (4), 6.8228 (4), 12.4237 (8)
α, β, γ (°)	83.116 (2), 87.975 (2), 88.854 (2)
$V(Å^3)$	569.05 (6)
Ζ	4
Radiation type	Μο Κα
$\mu (\text{mm}^{-1})$	16.20
Crystal size (mm)	$0.05 \times 0.03 \times 0.01$
Data collection	
Diffractometer	Stadi-Vari
Absorption correction	Numerical (<i>LANA</i> ; Koziskova <i>et</i>
ТТ	0.414, 0.808
¹ min, ¹ max No of measured independent and	23701 4046 3376
observed $[I > 2\sigma(I)]$ reflections	23771, 4040, 3370
R _{int}	0.035
$(\sin \theta / \lambda)_{\max} (\text{\AA}^{-1})$	0.767
Refinement	
$R[F^2 > 2\sigma(F^2)], wR(F^2), S$	0.030, 0.075, 1.00
No. of reflections	4046
No. of parameters	199
$\Delta \rho_{\rm max}, \Delta \rho_{\rm min} ({\rm e} \ {\rm \AA}^{-3})$	2.54, -2.81

Computer programs: X-AREA (Stoe, 2020), SHELXS97 and SHELXL97 (Sheldrick, 2008) and DIAMOND (Brandenburg & Putz, 2005).

a temperature of 1023 K, taking advantage of the presumed mineralizers Sb_2O_3 and $CeCl_3$. The transparent, colorless crystals exhibit a platelet-like habit.

Refinement

Crystal data, data collection and structure refinement details are summarized in Table 2.

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full crystallographic data

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H-type Ce₂[Si₂O₇]

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Dicerium(III) oxidodisilicate

Crystal data

Ce₂[Si₂O₇] $M_r = 448.42$ Triclinic, *P*1 Hall symbol: -P 1 a = 6.7671 (4) Å b = 6.8228 (4) Å c = 12.4237 (8) Å a = 83.116 (2)° $\beta = 87.975$ (2)° $\gamma = 88.854$ (2)° V = 569.05 (6) Å³

Data collection

Stadi-Vari diffractometer Radiation source: fine-focus sealed tube Graphite monochromator Detector resolution: 5.81 pixels mm⁻¹ DECTRIS PILATUS 200K scans Absorption correction: numerical (*LANA*; Koziskova *et al.*, 2016) $T_{\min} = 0.414, T_{\max} = 0.808$

Refinement

Refinement on F^2 Primary atom site lo
direct methodsLeast-squares matrix: fulldirect methods $R[F^2 > 2\sigma(F^2)] = 0.030$ Secondary atom site
map $wR(F^2) = 0.075$ mapS = 1.00 $w = 1/[\sigma^2(F_o^2) + (0.0$
where $P = (F_o^2 + 2)$ 4046 reflectionswhere $P = (F_o^2 + 2)$ 199 parameters $(\Delta/\sigma)_{max} < 0.001$
0 restraints $\Delta\rho_{max} = 2.54$ e Å⁻³
 $\Delta\rho_{min} = -2$ 81 e Å⁻³

Special details

Geometry. All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

Z = 4 F(000) = 800 $D_x = 5.234 \text{ Mg m}^{-3}$ Mo K α radiation, $\lambda = 0.71073 \text{ Å}$ Cell parameters from 23784 reflections $\theta = 1.7-33.1^{\circ}$ $\mu = 16.20 \text{ mm}^{-1}$ T = 293 K Platelet, colourless $0.05 \times 0.03 \times 0.01 \text{ mm}$

23791 measured reflections 4046 independent reflections 3376 reflections with $I > 2\sigma(I)$ $R_{int} = 0.035$ $\theta_{max} = 33.0^\circ, \ \theta_{min} = 1.7^\circ$ $h = -10 \rightarrow 10$ $k = -10 \rightarrow 10$ $l = -19 \rightarrow 19$

Primary atom site location: structure-invariant direct methods Secondary atom site location: difference Fourier map $w = 1/[\sigma^2(F_o^2) + (0.0498P)^2]$ where $P = (F_o^2 + 2F_c^2)/3$ $(\Delta/\sigma)_{max} < 0.001$ $\Delta\rho_{max} = 2.54 \text{ e } \text{Å}^{-3}$ $\Delta\rho_{min} = -2.81 \text{ e } \text{Å}^{-3}$ **Refinement**. Refinement of F² against ALL reflections. The weighted R-factor wR and goodness of fit S are based on F², conventional R-factors R are based on F, with F set to zero for negative F². The threshold expression of F² > 2sigma(F²) is used only for calculating R-factors(gt) etc. and is not relevant to the choice of reflections for refinement. R-factors based on F² are statistically about twice as large as those based on F, and R- factors based on ALL data will be even larger.

	x	У	Ζ	$U_{\rm iso}*/U_{\rm eq}$
Cel	0.23961 (4)	0.21088 (4)	0.35322 (2)	0.01505 (7)
Ce2	0.37019 (4)	0.36951 (4)	0.63911 (2)	0.01288 (7)
Ce4	0.07768 (4)	0.83629 (4)	0.15567 (2)	0.01239 (7)
Ce3	0.67603 (4)	0.23866 (4)	0.13758 (2)	0.01296 (7)
Si1	0.4321 (2)	0.2825 (2)	0.89563 (11)	0.0115 (2)
Si2	0.1605 (2)	0.3171 (2)	0.08912 (11)	0.0120 (2)
Si3	0.1616 (2)	0.6927 (2)	0.41176 (11)	0.0116 (2)
Si4	0.7737 (2)	0.1022 (2)	0.39232 (11)	0.0122 (2)
01	0.3784 (6)	0.8159 (5)	0.0460 (3)	0.0138 (7)
O2	0.4898 (6)	0.4620 (5)	0.8025 (3)	0.0142 (7)
O3	0.2938 (6)	0.1348 (5)	0.8380 (3)	0.0152 (7)
O4	0.3020 (6)	0.4046 (5)	0.9831 (3)	0.0144 (7)
05	0.0549 (6)	0.4850 (6)	0.1496 (3)	0.0204 (8)
O6	0.3068 (6)	0.1720 (5)	0.1671 (3)	0.0135 (7)
07	0.9958 (6)	0.1729 (6)	0.0479 (3)	0.0151 (7)
08	0.0207 (6)	0.3667 (6)	0.6549 (3)	0.0157 (7)
O9	0.2996 (6)	0.8508 (5)	0.3356 (3)	0.0161 (7)
O10	0.3069 (6)	0.5021 (5)	0.4473 (3)	0.0144 (7)
O11	0.9092 (6)	0.2162 (5)	0.4758 (3)	0.0140 (7)
O12	0.3041 (6)	0.0981 (6)	0.5432 (3)	0.0163 (7)
O13	0.5976 (6)	0.2494 (6)	0.3458 (3)	0.0156 (7)
014	0.9272 (6)	0.0858 (5)	0.2895 (3)	0.0152 (7)

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (A^2)

monuc displacement parameters (11)	Atomic	displ	lacement	parameters	$(Å^2)$
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	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
Cel	0.01240 (13)	0.01724 (13)	0.01669 (14)	-0.00301 (10)	0.00049 (10)	-0.00672 (10)
Ce2	0.01202 (13)	0.01287 (12)	0.01415 (13)	-0.00143 (9)	-0.00067 (10)	-0.00300 (9)
Ce4	0.01122 (13)	0.01164 (12)	0.01448 (13)	0.00012 (9)	0.00034 (9)	-0.00260 (9)
Ce3	0.01290 (13)	0.01218 (12)	0.01400 (13)	0.00150 (9)	0.00060 (10)	-0.00289 (9)
Si1	0.0113 (6)	0.0107 (6)	0.0129 (6)	-0.0003 (5)	-0.0001 (5)	-0.0034 (4)
Si2	0.0102 (6)	0.0121 (6)	0.0135 (6)	-0.0006 (5)	0.0002 (5)	-0.0015 (5)
Si3	0.0121 (6)	0.0099 (6)	0.0128 (6)	0.0008 (5)	-0.0011 (5)	-0.0018 (5)
Si4	0.0092 (6)	0.0148 (6)	0.0131 (6)	0.0026 (5)	-0.0011 (5)	-0.0041 (5)
01	0.0108 (16)	0.0161 (16)	0.0153 (17)	-0.0003 (13)	-0.0006 (13)	-0.0048 (13)
02	0.0168 (18)	0.0111 (15)	0.0150 (16)	-0.0021 (13)	-0.0014 (13)	-0.0019 (12)
O3	0.0141 (17)	0.0124 (16)	0.0202 (18)	-0.0004 (13)	-0.0037 (14)	-0.0058 (13)
O4	0.0132 (17)	0.0150 (16)	0.0147 (17)	-0.0007 (13)	0.0043 (13)	-0.0025 (13)
O5	0.021 (2)	0.0129 (17)	0.028 (2)	-0.0013 (15)	0.0074 (16)	-0.0077 (15)

data reports

O6	0.0129 (17)	0.0142 (16)	0.0135 (16)	0.0006 (13)	0.0004 (13)	-0.0032 (13)
O7	0.0149 (17)	0.0154 (16)	0.0158 (17)	-0.0025 (14)	-0.0009 (14)	-0.0044 (13)
O8	0.0119 (17)	0.0204 (18)	0.0159 (17)	-0.0027 (14)	-0.0009 (13)	-0.0058 (14)
09 010 011	0.0142 (18) 0.0152 (18) 0.0144 (17)	0.0142 (17) 0.0130 (16) 0.0149 (16)	0.0195 (18) 0.0150 (17) 0.0141 (16)	0.0007 (13) 0.0036 (13) -0.0007 (13) 0.0027 (14)	0.0016 (14) 0.0010 (13) 0.0008 (13)	-0.0003 (13) -0.0023 (13) -0.0074 (13) 0.0022 (12)
012	0.0139 (19)	0.0148 (17)	0.0130 (17)	-0.0027 (14)	$\begin{array}{c} -0.0010 (14) \\ -0.0042 (14) \\ 0.0006 (14) \end{array}$	-0.0032 (13)
013	0.0131 (17)	0.0162 (17)	0.0169 (17)	0.0012 (13)		0.0013 (13)
014	0.0130 (17)	0.0132 (16)	0.0192 (18)	-0.0012 (13)		-0.0018 (13)

Geometric parameters (Å, °)

Ce1—O6	2.386 (4)	Ce3—Si1 ^x	3.4591 (15)
Ce1—O13	2.439 (4)	Si1—O1 ⁱⁱⁱ	1.592 (4)
Ce1—O12	2.445 (4)	Si1—O2	1.624 (4)
Ce1—O10	2.480 (4)	Si1—O3	1.632 (4)
Ce1—O14 ⁱ	2.486 (4)	Si1—O4	1.664 (4)
Ce1—O9 ⁱⁱ	2.516 (4)	Si1—Ce3 ⁱⁱⁱ	3.3138 (14)
Ce1—O11 ⁱ	2.663 (4)	Sil—Ce4 ⁱⁱⁱ	3.4549 (14)
Ce1—Si4 ⁱ	3.2597 (15)	Si1—Ce3 ^{xi}	3.4591 (15)
Ce1—Si2	3.3340 (15)	Si2—O5	1.589 (4)
Ce1—Si3	3.4775 (14)	Si2—O7 ⁱ	1.636 (4)
Ce1—Ce3	3.9086 (4)	Si2—O6	1.642 (4)
Ce1—Ce4 ⁱⁱ	3.9449 (4)	Si2—O4 ^x	1.660 (4)
Ce2—O8	2.366 (4)	Si2—Ce4 ⁱⁱ	3.3391 (14)
Ce2—O2	2.370 (4)	Si2—Ce3 ⁱ	3.3544 (14)
Ce2—O12	2.376 (4)	Si3—O8 ^v	1.595 (4)
Ce2—O10	2.494 (4)	Si3—O9	1.632 (4)
Ce2—O10 ⁱⁱⁱ	2.526 (4)	Si3—O10	1.641 (4)
Ce2—O13 ⁱⁱⁱ	2.643 (4)	Si3—O11 ⁱⁱⁱ	1.648 (4)
Ce2—O9 ⁱⁱⁱ	2.675 (4)	Si3—Ce2 ⁱⁱⁱ	3.2386 (15)
Ce2—O3	2.817 (4)	Si4—O12 ^{iv}	1.588 (4)
Ce2—Si1	3.2118 (14)	Si4—O13	1.620 (4)
Ce2—Si3 ⁱⁱⁱ	3.2386 (15)	Si4—O14	1.631 (4)
Ce2—Si4 ^{iv}	3.4514 (15)	Si4—O11	1.676 (4)
Ce2—Ce1 ⁱⁱⁱ	3.9450 (4)	Si4—Ce1 ^{ix}	3.2597 (15)
Ce4—O5	2.415 (4)	Si4—Ce2 ^{iv}	3.4514 (15)
Ce4—O1	2.420 (4)	O1—Si1 ⁱⁱⁱ	1.593 (4)
Ce4—O3 ^v	2.517 (4)	O1—Ce3 ^{vii}	2.396 (4)
Ce4—O7 ^{vi}	2.576 (4)	O2—Ce3 ⁱⁱⁱ	2.490 (4)
Ce4—O7 ^{vii}	2.603 (4)	O3—Ce4 ^v	2.517 (4)
Ce4—O8 ^v	2.655 (4)	O3—Ce3 ^{iv}	2.534 (4)
Ce4—O14 ^{vi}	2.681 (4)	O4—Si2 ^{xi}	1.660 (4)
Ce4—O9	2.749 (4)	O4—Ce3 ⁱⁱⁱ	2.705 (4)
Ce4—O6 ^{viii}	2.812 (4)	O6—Ce4 ⁱⁱ	2.812 (4)
Ce4—Si3	3.2807 (14)	O7—Si2 ^{ix}	1.636 (4)
Ce4—Si2 ^{viii}	3.3391 (14)	O7—Ce4 ^{xii}	2.576 (4)
Ce4—Si1 ⁱⁱⁱ	3.4549 (14)	O7—Ce4 ^{vii}	2.603 (4)

Ce3—O1 ^{vii}	2.396 (4)	O8—Si3 ^v	1.595 (4)
Ce3—O7	2.457 (4)	O8—Ce4 ^v	2.655 (4)
Ce3—O2 ⁱⁱⁱ	2.490 (4)	O9—Ce1 ^{viii}	2.516 (4)
Ce3—O3 ^{iv}	2.534 (4)	O9—Ce2 ⁱⁱⁱ	2.675 (4)
Ce3—06	2.555 (4)	O10—Ce2 ⁱⁱⁱ	2.526 (4)
$Ce_3 = 013$	2.632(4)	011 - 53	1.648(4)
Ce_{3} 014	2.632(1) 2.687(4)	$O11$ Ce^{1ix}	2 663 (4)
$C_{2}^{3} O_{1}^{iii}$	2.007(4)	O12 Sidiv	2.003(4)
C_{23} Si4	2.703(+)	O12 - O12	1.500(4)
$C_{e3} = 514$	3.2707(13)	$O13 - Ce2^{m}$	2.043(4)
	3.3138 (14)		2.486 (4)
$Ce3-Si2^{ix}$	3.3545 (14)	O14—Ce4 ^{xii}	2.681 (4)
O6—Ce1—O13	80.46 (13)	$O1^{vn}$ —Ce3—O13	158.15 (12)
O6—Ce1—O12	147.59 (13)	O7—Ce3—O13	128.05 (12)
O13—Ce1—O12	81.45 (13)	O2 ⁱⁱⁱ —Ce3—O13	61.06 (12)
O6—Ce1—O10	127.63 (12)	O3 ^{iv} —Ce3—O13	92.21 (12)
O13—Ce1—O10	73.40 (13)	O6—Ce3—O13	73.85 (12)
O12-Ce1-O10	71.25 (12)	O1 ^{vii} —Ce3—O14	134.41 (12)
O6-Ce1-014 ⁱ	75.12 (13)	O7—Ce3—O14	71.46 (12)
O13—Ce1—O14 ⁱ	152.98 (13)	O2 ⁱⁱⁱ —Ce3—O14	109.22 (12)
O12—Ce1—O14 ⁱ	113.96 (13)	O3 ^{iv} —Ce3—O14	64.76 (12)
O10-Ce1-O14 ⁱ	131.49 (12)	O6—Ce3—O14	119.09 (12)
06—Ce1—O9 ⁱⁱ	70.85 (13)	O13—Ce3—O14	58.17 (12)
013—Ce1—O9 ⁱⁱ	87 75 (13)	01^{vii} Ce3 04^{vii}	73 44 (12)
$012 - Ce1 - O9^{ii}$	81 79 (12)	07 —Ce3— 04^{iii}	84 49 (12)
$012 - Ce1 - O9^{ii}$	148 87 (13)	$0^{2^{11}}$ Ce3 $0^{4^{11}}$	58 16 (11)
014^{i} Cel 09^{ii}	73 55 (13)	O_2^{iv} Ce ³ O_4^{iii}	152 59 (11)
$06 Cel 011^{i}$	133.66(12)	$O_{1} = C_{2} = O_{1}$	105.35(11)
	135.00(12) 145.82(12)	012 Co2 04^{iii}	105.55(12)
012 Col 011	(143.82(12))	$013 - Ce_{3} - 04^{iii}$	113.11(11)
	09.02(12)	014 - 023 - 04	127.02(11)
	80.90 (11)	01^{-1} Ce3—S14	154.61 (9)
	59.92 (12)	$0/-Ce_3-Si_4$	101.12 (9)
$O9^n$ —Cel—O11 ¹	104.08 (12)	$O2^{m}$ —Ce3—S14	87.58 (9)
O6—Cel—Si4 ¹	104.09 (9)	$O3^{1v}$ —Ce3—Si4	72.78 (9)
O13—Ce1—Si4 ¹	171.06 (9)	O6—Ce3—Si4	93.50 (9)
O12—Ce1—Si4 ⁱ	90.92 (10)	O13—Ce3—Si4	29.31 (9)
O10—Ce1—Si4 ⁱ	108.63 (9)	O14—Ce3—Si4	29.70 (8)
O14 ⁱ —Ce1—Si4 ⁱ	29.22 (9)	O4 ⁱⁱⁱ —Ce3—Si4	130.95 (8)
O9 ⁱⁱ —Ce1—Si4 ⁱ	86.55 (9)	O1 ^{vii} —Ce3—Si1 ⁱⁱⁱ	96.03 (9)
O11 ⁱ —Ce1—Si4 ⁱ	30.83 (8)	O7—Ce3—Si1 ⁱⁱⁱ	110.56 (9)
O6—Ce1—Si2	27.50 (9)	O2 ⁱⁱⁱ —Ce3—Si1 ⁱⁱⁱ	28.21 (9)
O13—Ce1—Si2	98.21 (9)	O3 ^{iv} —Ce3—Si1 ⁱⁱⁱ	171.84 (9)
O12—Ce1—Si2	174.13 (9)	O6—Ce3—Si1 ⁱⁱⁱ	88.46 (9)
O10—Ce1—Si2	114.33 (9)	O13—Ce3—Si1 ⁱⁱⁱ	86.88 (9)
O14 ⁱ —Ce1—Si2	64.12 (9)	O14—Ce3—Si1 ⁱⁱⁱ	121.00 (8)
O9 ⁱⁱ —Ce1—Si2	92.34 (9)	O4 ⁱⁱⁱ —Ce3—Si1 ⁱⁱⁱ	29.98 (8)
$O11^{i}$ —Ce1—Si2	112.92 (9)	Si4—Ce3—Si1 ⁱⁱⁱ	109.25 (3)
$Si4^{i}$ Ce1—Si2	88 90 (4)	01^{vii} Ce3 Si2 ^{ix}	93 12 (9)
011 001 012	(1) (1)	01 003 -012	13.14 (9)

O6—Ce1—Si3	116.03 (9)	O7—Ce3—Si2 ^{ix}	27.57 (9)
O13—Ce1—Si3	91.87 (10)	O2 ⁱⁱⁱ —Ce3—Si2 ^{ix}	110.34 (9)
O12—Ce1—Si3	91.19 (9)	O3 ^{iv} —Ce3—Si2 ^{ix}	95.45 (9)
O10—Ce1—Si3	25.65 (9)	O6—Ce3—Si2 ^{ix}	177.57 (8)
O14 ⁱ —Ce1—Si3	109.06 (9)	O13—Ce3—Si2 ^{ix}	108.41 (9)
O9 ⁱⁱ —Ce1—Si3	172.95 (9)	O14—Ce3—Si2 ^{ix}	62.18 (8)
O11 ⁱ —Ce1—Si3	72.54 (8)	O4 ⁱⁱⁱ —Ce3—Si2 ^{ix}	74.63 (9)
Si4 ⁱ —Ce1—Si3	92.94 (3)	Si4—Ce3—Si2 ^{ix}	88.27 (4)
Si2—Ce1—Si3	94.68 (3)	Si1 ⁱⁱⁱ —Ce3—Si2 ^{ix}	92.53 (3)
O6—Ce1—Ce3	39.25 (9)	O1 ^{vii} —Ce3—Si1 ^x	23.77 (9)
O13—Ce1—Ce3	41.41 (9)	O7—Ce3—Si1 ^x	92.53 (9)
O12—Ce1—Ce3	119.59 (9)	O2 ⁱⁱⁱ —Ce3—Si1 ^x	93.20 (9)
O10—Ce1—Ce3	100.84 (9)	O3 ^{iv} —Ce3—Si1 ^x	96.79 (9)
O14 ⁱ —Ce1—Ce3	114.11 (9)	O6—Ce3—Si1 ^x	68.02 (9)
O9 ⁱⁱ —Ce1—Ce3	78.88 (9)	O13—Ce3—Si1 ^x	139.39 (9)
O11 ⁱ —Ce1—Ce3	171.37 (9)	O14—Ce3—Si1 ^x	157.57 (8)
Si4 ⁱ —Ce1—Ce3	143.27 (3)	O4 ⁱⁱⁱ —Ce3—Si1 ^x	64.36 (8)
Si2—Ce1—Ce3	58.60 (3)	Si4—Ce3—Si1 ^x	160.04 (4)
Si3—Ce1—Ce3	105.38 (2)	Si1 ⁱⁱⁱ —Ce3—Si1 ^x	78.82 (4)
O6—Ce1—Ce4 ⁱⁱ	44.83 (9)	$Si2^{ix}$ —Ce3—Si1 ^x	110.00 (3)
O13—Ce1—Ce4 ⁱⁱ	111.23 (9)	$O1^{iii}$ —Si1—O2	112.2 (2)
O12—Ce1—Ce4 ⁱⁱ	120.79 (9)	$O1^{iii}$ —Si1—O3	116.1 (2)
O10—Ce1—Ce4 ⁱⁱ	167.15 (9)	02—Si1—O3	106.2 (2)
O14 ⁱ —Ce1—Ce4 ⁱⁱ	42.09 (9)	$O1^{iii}$ —Si1—O4	108.8 (2)
O9 ⁱⁱ —Ce1—Ce4 ⁱⁱ	43.77 (9)	O2—Si1—O4	100.67 (19)
O11 ⁱ —Ce1—Ce4 ⁱⁱ	98.80 (8)	O3—Si1—O4	111.8 (2)
Si4 ⁱ —Ce1—Ce4 ⁱⁱ	68.76 (2)	O1 ⁱⁱⁱ —Si1—Ce2	126.94 (14)
Si2—Ce1—Ce4 ⁱⁱ	53.82 (2)	O2—Si1—Ce2	45.33 (13)
Si3—Ce1—Ce4 ⁱⁱ	142.11 (3)	O3—Si1—Ce2	61.23 (15)
Ce3—Ce1—Ce4 ⁱⁱ	77.595 (9)	O4—Si1—Ce2	121.26 (15)
O8—Ce2—O2	107.78 (13)	O1 ⁱⁱⁱ —Si1—Ce3 ⁱⁱⁱ	125.40 (15)
O8—Ce2—O12	79.73 (13)	O2—Si1—Ce3 ⁱⁱⁱ	46.43 (13)
O2—Ce2—O12	144.59 (13)	O3—Si1—Ce3 ⁱⁱⁱ	118.24 (15)
08—Ce2—O10	83.10 (13)	O4—Si1—Ce3 ⁱⁱⁱ	54.31 (13)
O2—Ce2—O10	142.07 (12)	Ce2—Si1—Ce3 ⁱⁱⁱ	77.32 (3)
012—Ce2—O10	72.15 (13)	$O1^{iii}$ —Si1—Ce4 ⁱⁱⁱ	38.46 (14)
08—Ce2—010 ⁱⁱⁱ	152.66 (13)	O2—Si1—Ce4 ⁱⁱⁱ	79.83 (15)
$02-Ce^2-010^{iii}$	85.76 (13)	O3—Si1—Ce4 ⁱⁱⁱ	108.61 (15)
012—Ce2—O10 ⁱⁱⁱ	103.20 (12)	O4—Si1—Ce4 ⁱⁱⁱ	137.53 (15)
010 —Ce2— 010^{iii}	72.34 (14)	Ce2—Si1—Ce4 ⁱⁱⁱ	89.45 (3)
$08-Ce^2-013^{iii}$	95 55 (13)	Ce ³ ⁱⁱⁱ —Si1—Ce ⁴ ⁱⁱⁱ	114 92 (4)
$02 - Ce^2 - 013^{iii}$	62 31 (12)	01^{iii} Si1 Ce 3^{xi}	37 34 (13)
012—Ce2—O13 ⁱⁱⁱ	152.92(13)	02—Si1—Ce3 ^{xi}	118 77 (15)
$010 - Ce^2 - 013^{iii}$	80.83 (12)	03 —Si1—Ce 3^{xi}	133.73 (16)
010^{iii} —Ce2—013 ⁱⁱⁱ	69 29 (12)	04 —Si1—Ce 3^{xi}	71 50 (14)
$08-Ce^2-O^{9iii}$	144 80 (13)	Ce^2 —Si1— Ce^{3xi}	158 39 (5)
$02 - Ce^2 - O^{3ii}$	77 89 (13)	$Ce^{3^{iii}}$ Sil—Ce 3^{xi}	101 18 (4)
$012 - Ce^2 - O^{9iii}$	77 40 (13)	$Ce4^{iii}$ —Si1—Ce3 ^{xi}	71 44 (3)
012 -002-07	(15)		(3) דד.1

O10—Ce2—O9 ⁱⁱⁱ	114.27 (12)	O5—Si2—O7 ⁱ	110.3 (2)
O10 ⁱⁱⁱ —Ce2—O9 ⁱⁱⁱ	60.08 (12)	O5—Si2—O6	113.3 (2)
O13 ⁱⁱⁱ —Ce2—O9 ⁱⁱⁱ	116.64 (12)	O7 ⁱ —Si2—O6	105.8 (2)
O8—Ce2—O3	76.47 (13)	O5—Si2—O4 ^x	113.3 (2)
O2—Ce2—O3	59.52 (11)	O7 ⁱ —Si2—O4 ^x	108.5 (2)
O12—Ce2—O3	90.43 (12)	O6—Si2—O4 ^x	105.2 (2)
O10—Ce2—O3	155.27 (12)	O5—Si2—Ce1	72.52 (17)
O10 ⁱⁱⁱ —Ce2—O3	130.15 (12)	O7 ⁱ —Si2—Ce1	111.94 (15)
O13 ⁱⁱⁱ —Ce2—O3	114.59 (11)	O6—Si2—Ce1	42.13 (13)
O9 ⁱⁱⁱ —Ce2—O3	77.30 (11)	O4 ^x —Si2—Ce1	133.61 (15)
O8—Ce2—Si1	94.61 (10)	O5—Si2—Ce4 ⁱⁱ	123.40 (16)
O2—Ce2—Si1	29.17 (9)	O7 ⁱ —Si2—Ce4 ⁱⁱ	48.86 (14)
O12—Ce2—Si1	118.01 (10)	O6—Si2—Ce4 ⁱⁱ	57.20 (13)
O10—Ce2—Si1	169.12 (8)	O4 ^x —Si2—Ce4 ⁱⁱ	123.07 (14)
O10 ⁱⁱⁱ —Ce2—Si1	107.23 (9)	Ce1—Si2—Ce4 ⁱⁱ	72.48 (3)
O13 ⁱⁱⁱ —Ce2—Si1	88.84 (9)	O5—Si2—Ce3 ⁱ	67.40 (16)
O9 ⁱⁱⁱ —Ce2—Si1	73.43 (9)	O7 ⁱ —Si2—Ce3 ⁱ	44.01 (14)
O3—Ce2—Si1	30.51 (8)	O6—Si2—Ce3 ⁱ	114.70 (14)
O8—Ce2—Si3 ⁱⁱⁱ	169.04 (9)	O4 ^x —Si2—Ce3 ⁱ	135.93 (15)
O2—Ce2—Si3 ⁱⁱⁱ	81.72 (10)	Ce1—Si2—Ce3 ⁱ	89.90 (3)
O12—Ce2—Si3 ⁱⁱⁱ	89.35 (10)	Ce4 ⁱⁱ —Si2—Ce3 ⁱ	69.54 (3)
O10—Ce2—Si3 ⁱⁱⁱ	92.69 (9)	O8 ^v —Si3—O9	109.9 (2)
O10 ⁱⁱⁱ —Ce2—Si3 ⁱⁱⁱ	29.96 (9)	O8 ^v —Si3—O10	111.7 (2)
O13 ⁱⁱⁱ —Ce2—Si3 ⁱⁱⁱ	93.75 (9)	O9—Si3—O10	105.6 (2)
O9 ⁱⁱⁱ —Ce2—Si3 ⁱⁱⁱ	30.16 (9)	O8 ^v —Si3—O11 ⁱⁱⁱ	112.5 (2)
O3—Ce2—Si3 ⁱⁱⁱ	104.81 (8)	O9—Si3—O11 ⁱⁱⁱ	110.1 (2)
Si1—Ce2—Si3 ⁱⁱⁱ	91.36 (4)	O10—Si3—O11 ⁱⁱⁱ	106.8 (2)
O8—Ce2—Si4 ^{iv}	72.98 (10)	O8 ^v —Si3—Ce2 ⁱⁱⁱ	128.57 (15)
O2—Ce2—Si4 ^{iv}	123.96 (9)	O9—Si3—Ce2 ⁱⁱⁱ	55.43 (14)
O12—Ce2—Si4 ^{iv}	23.56 (9)	O10—Si3—Ce2 ⁱⁱⁱ	50.22 (14)
O10—Ce2—Si4 ^{iv}	93.93 (9)	O11 ⁱⁱⁱ —Si3—Ce2 ⁱⁱⁱ	118.79 (15)
O10 ⁱⁱⁱ —Ce2—Si4 ^{iv}	119.59 (8)	O8 ^v —Si3—Ce4	53.26 (15)
O13 ⁱⁱⁱ —Ce2—Si4 ^{iv}	167.97 (9)	O9—Si3—Ce4	56.77 (15)
O9 ⁱⁱⁱ —Ce2—Si4 ^{iv}	75.37 (9)	O10—Si3—Ce4	121.00 (14)
O3—Ce2—Si4 ^{iv}	66.98 (8)	O11 ⁱⁱⁱ —Si3—Ce4	132.16 (15)
Si1—Ce2—Si4 ^{iv}	95.56 (3)	Ce2 ⁱⁱⁱ —Si3—Ce4	92.12 (4)
Si3 ⁱⁱⁱ —Ce2—Si4 ^{iv}	97.33 (3)	O8 ^v —Si3—Ce1	71.73 (15)
O8—Ce2—Ce1 ⁱⁱⁱ	132.77 (9)	O9—Si3—Ce1	112.56 (14)
O2—Ce2—Ce1 ⁱⁱⁱ	56.85 (9)	O10—Si3—Ce1	40.86 (13)
O12—Ce2—Ce1 ⁱⁱⁱ	140.76 (9)	O11 ⁱⁱⁱ —Si3—Ce1	132.06 (15)
O10—Ce2—Ce1 ⁱⁱⁱ	88.69 (9)	Ce2 ⁱⁱⁱ —Si3—Ce1	71.85 (3)
O10 ⁱⁱⁱ —Ce2—Ce1 ⁱⁱⁱ	37.59 (8)	Ce4—Si3—Ce1	90.17 (3)
O13 ⁱⁱⁱ —Ce2—Ce1 ⁱⁱⁱ	37.25 (9)	O12 ^{iv} —Si4—O13	113.3 (2)
O9 ⁱⁱⁱⁱ —Ce2—Ce1 ⁱⁱⁱ	80.15 (8)	O12 ^{iv} —Si4—O14	117.4 (2)
O3—Ce2—Ce1 ⁱⁱⁱ	115.42 (8)	O13—Si4—O14	105.4 (2)
Si1—Ce2—Ce1 ⁱⁱⁱ	85.07 (3)	O12 ^{iv} —Si4—O11	108.3 (2)
Si3 ⁱⁱⁱ —Ce2—Ce1 ⁱⁱⁱ	56.89 (2)	O13—Si4—O11	109.4 (2)
Si4 ^{iv} —Ce2—Ce1 ⁱⁱⁱ	154.20 (3)	O14—Si4—O11	102.3 (2)

O5—Ce4—O1	85.88 (13)	O12 ^{iv} —Si4—Ce1 ^{ix}	124.17 (16)
O5—Ce4—O3 ^v	89.90 (13)	O13—Si4—Ce1 ^{ix}	122.54 (15)
O1—Ce4—O3 ^v	147.59 (13)	O14—Si4—Ce1 ^{ix}	48.06 (14)
O5Ce4O7 ^{vi}	142.34 (14)	O11—Si4—Ce1 ^{ix}	54.50 (13)
O1—Ce4—O7 ^{vi}	89.55 (12)	O12 ^{iv} —Si4—Ce3	122.57 (15)
O3 ^v —Ce4—O7 ^{vi}	74.52 (12)	O13—Si4—Ce3	52.68 (14)
O5Ce4O7 ^{vii}	79.14 (14)	O14—Si4—Ce3	54.71 (15)
O1—Ce4—O7 ^{vii}	68.22 (12)	O11—Si4—Ce3	129.08 (15)
O3 ^v —Ce4—O7 ^{vii}	79.42 (12)	Cel ^{ix} —Si4—Ce3	92.60 (4)
O7 ^{vi} —Ce4—O7 ^{vii}	64.55 (13)	O12 ^{iv} —Si4—Ce2 ^{iv}	36.72 (14)
O5—Ce4—O8 ^v	66.01 (13)	O13—Si4—Ce2 ^{iv}	106.37 (15)
O1—Ce4—O8 ^v	128.92 (13)	O14—Si4—Ce2 ^{iv}	86.82 (14)
O3 ^v —Ce4—O8 ^v	77.17 (12)	O11—Si4—Ce2 ^{iv}	138.90 (15)
$O7^{vi}$ —Ce4—O8 ^v	138.50 (12)	Ce1 ^{ix} —Si4—Ce2 ^{iv}	118.44 (4)
$O7^{vii}$ —Ce4—O8 ^v	137.57 (12)	Ce3—Si4—Ce2 ^{iv}	88.97 (3)
O5—Ce4—O14 ^{vi}	134.07 (13)	Si1 ⁱⁱⁱ —O1—Ce3 ^{vii}	118.88 (19)
O1—Ce4—O14 ^{vi}	135.66 (12)	Sil ⁱⁱⁱ —O1—Ce4	117.4 (2)
O3 ^v —Ce4—O14 ^{vi}	65.09 (12)	Ce3 ^{vii} —O1—Ce4	113.89 (15)
$O7^{vi}$ —Ce4—O14 ^{vi}	69.81 (12)	Si1—O2—Ce2	105.51 (18)
O7 ^{vii} —Ce4—O14 ^{vi}	127.90 (12)	Si1—O2—Ce3 ⁱⁱⁱ	105.37 (18)
O8 ^v —Ce4—O14 ^{vi}	70.98 (12)	Ce2—O2—Ce3 ⁱⁱⁱ	114.04 (15)
O5—Ce4—O9	101.90 (14)	Si1—O3—Ce4 ^v	122.03 (19)
O1—Ce4—O9	89.74 (12)	Si1—O3—Ce3 ^{iv}	125.0 (2)
O3 ^v —Ce4—O9	122.51 (12)	Ce4 ^v —O3—Ce3 ^{iv}	98.17 (13)
O7 ^{vi} —Ce4—O9	115.46 (11)	Si1—O3—Ce2	88.26 (16)
O7 ^{vii} —Ce4—O9	157.89 (12)	Ce4 ^v —O3—Ce2	98.75 (13)
O8 ^v —Ce4—O9	58.52 (12)	Ce3 ^{iv} —O3—Ce2	123.54 (14)
O14 ^{vi} —Ce4—O9	66.93 (12)	Si2 ^{xi} —O4—Si1	129.2 (2)
O5—Ce4—O6 ^{viii}	150.12 (13)	Si2 ^{xi} —O4—Ce3 ⁱⁱⁱ	133.16 (19)
O1—Ce4—O6 ^{viii}	70.33 (11)	Si1—O4—Ce3 ⁱⁱⁱ	95.71 (16)
O3 ^v —Ce4—O6 ^{viii}	119.89 (11)	Si2—O5—Ce4	138.9 (2)
O7 ^{vi} —Ce4—O6 ^{viii}	57.87 (11)	Si2—O6—Ce1	110.37 (18)
O7 ^{vii} —Ce4—O6 ^{viii}	106.96 (11)	Si2—O6—Ce3	115.34 (19)
O8 ^v —Ce4—O6 ^{viii}	115.35 (11)	Ce1—O6—Ce3	104.53 (14)
$O14^{vi}$ —Ce4— $O6^{viii}$	65.44 (11)	Si2—O6—Ce4 ⁱⁱ	93.40 (16)
O9—Ce4—O6 ^{viii}	61.50 (11)	Ce1—O6—Ce4 ⁱⁱ	98.43 (12)
O5—Ce4—Si3	82.23 (11)	Ce3—O6—Ce4 ⁱⁱ	132.92 (14)
O1—Ce4—Si3	110.48 (9)	Si2 ^{ix} —O7—Ce3	108.42 (18)
O3 ^v —Ce4—Si3	100.71 (9)	Si2 ^{ix} —O7—Ce4 ^{xii}	102.57 (19)
O7 ^{vi} —Ce4—Si3	133.72 (8)	Ce3—O7—Ce4 ^{xii}	98.63 (13)
O7 ^{vii} —Ce4—Si3	161.37 (9)	Si2 ^{ix} —O7—Ce4 ^{vii}	123.2 (2)
O8 ^v —Ce4—Si3	28.79 (9)	Ce3—O7—Ce4 ^{vii}	105.80 (14)
O14 ^{vi} —Ce4—Si3	66.87 (9)	Ce4 ^{xii} —O7—Ce4 ^{vii}	115.45 (13)
O9—Ce4—Si3	29.77 (8)	Si3 ^v —O8—Ce2	138.7 (2)
O6 ^{viii} —Ce4—Si3	89.27 (8)	Si3 ^v —O8—Ce4 ^v	97.95 (18)
O5—Ce4—Si2 ^{viii}	163.01 (10)	Ce2—O8—Ce4 ^v	107.50 (15)
O1—Ce4—Si2 ^{viii}	80.50 (9)	Si3—O9—Ce1 ^{viii}	117.11 (19)
O3 ^v —Ce4—Si2 ^{viii}	96.17 (9)	Si3—O9—Ce2 ⁱⁱⁱ	94.41 (17)

O7 ^{vi} —Ce4—Si2 ^{viii}	28.57 (9)	Ce1 ^{viii} —O9—Ce2 ⁱⁱⁱ	130.18 (16)
O7 ^{vii} —Ce4—Si2 ^{viii}	86.37 (9)	Si3—O9—Ce4	93.46 (17)
O8 ^v —Ce4—Si2 ^{viii}	130.82 (8)	Ce1 ^{viii} —O9—Ce4	96.94 (13)
O14 ^{vi} —Ce4—Si2 ^{viii}	62.47 (8)	Ce2 ⁱⁱⁱ —O9—Ce4	119.87 (14)
O9—Ce4—Si2 ^{viii}	88.21 (8)	Si3—O10—Ce1	113.49 (19)
O6 ^{viii} —Ce4—Si2 ^{viii}	29.40 (8)	Si3—O10—Ce2	124.03 (18)
Si3—Ce4—Si2 ^{viii}	112.00 (3)	Ce1—O10—Ce2	105.83 (14)
O5—Ce4—Si1 ⁱⁱⁱ	79.59 (10)	Si3—O10—Ce2 ⁱⁱⁱ	99.82 (17)
O1—Ce4—Si1 ⁱⁱⁱ	24.16 (9)	Ce1—O10—Ce2 ⁱⁱⁱ	104.00 (12)
O3 ^v —Ce4—Si1 ⁱⁱⁱ	166.44 (8)	Ce2—O10—Ce2 ⁱⁱⁱ	107.66 (14)
O7 ^{vi} —Ce4—Si1 ⁱⁱⁱ	108.85 (9)	Si3 ⁱⁱⁱ —O11—Si4	128.8 (2)
O7 ^{vii} —Ce4—Si1 ⁱⁱⁱ	90.11 (9)	Si3 ⁱⁱⁱ —O11—Ce1 ^{ix}	136.4 (2)
O8 ^v —Ce4—Si1 ⁱⁱⁱ	105.82 (9)	Si4—O11—Ce1 ^{ix}	94.67 (15)
O14 ^{vi} —Ce4—Si1 ⁱⁱⁱ	128.47 (9)	Si4 ^{iv} —O12—Ce2	119.7 (2)
O9—Ce4—Si1 ⁱⁱⁱ	68.63 (8)	Si4 ^{iv} —O12—Ce1	124.8 (2)
O6 ^{viii} —Ce4—Si1 ⁱⁱⁱ	71.29 (8)	Ce2—O12—Ce1	110.77 (15)
Si3—Ce4—Si1 ⁱⁱⁱ	86.45 (3)	Si4—O13—Ce1	131.2 (2)
Si2 ^{viii} —Ce4—Si1 ⁱⁱⁱ	91.70 (3)	Si4—O13—Ce3	98.00 (18)
O1 ^{vii} —Ce3—O7	71.08 (13)	Ce1—O13—Ce3	100.78 (13)
O1 ^{vii} —Ce3—O2 ⁱⁱⁱ	115.42 (13)	Si4—O13—Ce2 ⁱⁱⁱ	118.1 (2)
O7—Ce3—O2 ⁱⁱⁱ	134.51 (12)	Ce1—O13—Ce2 ⁱⁱⁱ	101.75 (14)
O1 ^{vii} —Ce3—O3 ^{iv}	81.85 (13)	Ce3—O13—Ce2 ⁱⁱⁱ	101.24 (13)
O7—Ce3—O3 ^{iv}	76.31 (12)	Si4—O14—Ce1 ^{ix}	102.72 (18)
O2 ⁱⁱⁱ —Ce3—O3 ^{iv}	147.15 (12)	Si4—O14—Ce4 ^{xii}	143.4 (2)
O1 ^{vii} —Ce3—O6	84.56 (12)	Ce1 ^{ix} —O14—Ce4 ^{xii}	99.49 (13)
O7—Ce3—O6	150.12 (11)	Si4—O14—Ce3	95.60 (18)
O2 ⁱⁱⁱ —Ce3—O6	71.43 (12)	Ce1 ^{ix} —O14—Ce3	131.95 (15)
O3 ^{iv} —Ce3—O6	83.50 (12)	Ce4 ^{xii} —O14—Ce3	90.65 (12)

Symmetry codes: (i) *x*-1, *y*, *z*; (ii) *x*, *y*-1, *z*; (iii) -*x*+1, -*y*+1, -*z*+1; (iv) -*x*+1, -*y*, -*z*+1; (v) -*x*, -*y*+1, -*z*+1; (vi) *x*-1, *y*+1, *z*; (vii) -*x*+1, -*y*+1, -*z*; (viii) *x*, *y*+1, *z*; (ix) *x*+1, *y*, *z*; (ix) *x*, *y*, *z*-1; (ix) *x*+1, *y*-1, *z*.